

30857 U.S. PTO
10/058353
01/30/2002

PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10058353	FILING DATE 01/30/2002	CLASS 117	SUBCLASS 104	GAU 1765	EXAMINER JOC
**APPLICANTS: Oguri Emi; Hirose Fusao; Kuno Hironari; Nagakubo Masao; Onda Shoichi;					
**CONTINUING DATA VERIFIED: none M7					
BEST AVAILABLE COPY					
** FOREIGN APPLICATIONS VERIFIED: JAPAN 2001-30477 02/07/2001 M7					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Foreign prio.../ claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO	
Verified and Acknowledged Examiners's initials M7				01-251	
TITLE : Silicon carbide single crystal and process for producing the same					

U.S. DEPT. OF COMM./PAT & TM-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		Assistant Examiner		CLAIMS ALLOWED	
				Total Claims	Print Claim for O.G.
ISSUE FEE		Primary Examiner	DRAWING		
Amount Due	Date Paid		Sheets Drwg.	Figs. Drwg.	Print Fig.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	Application Examiner		
WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.					

FILED WITH:

☐ DISK (CRF)

☐ CD-ROM

(Attached in pocket on right inside flap)